## NSN 5961-01-422-6529

Transistor - Page 1 of 1

**Demilitarization:** Yes - demil/mli

**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-422-6529 **Inclosure Material:** Plastic **Overall Length:** 0.119 inches **Overall Height:** 0.061 inches **Overall Width:** 0.103 inches **Internal Configuration:** Field effect-dual gate **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 drain to source voltage **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current of standard range **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 37695-647468 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 printed circuit Shelf Life: N/a **Unit Of Measure:**